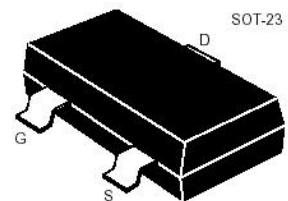


N-Channel Power MOSFET



■MAXIMUM RATINGS

Characteristic	Symbol	Max	Unit
Drain-Source Voltage	BV_{DSS}	100	V
Gate- Source Voltage	V_{GS}	± 20	V
Drain Current.continuous	I_{DR}	150	mA
Drain Current-pulsed	I_{DRM}	600	mA

■THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A=25^\circ C$ Derate above $25^\circ C$	P_D	250	mW
		1.8	$mW/^\circ C$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	500	$^\circ C/W$
Junction and Storage Temperature	T_J, T_{stg}	150°C, -55 to +150°C	

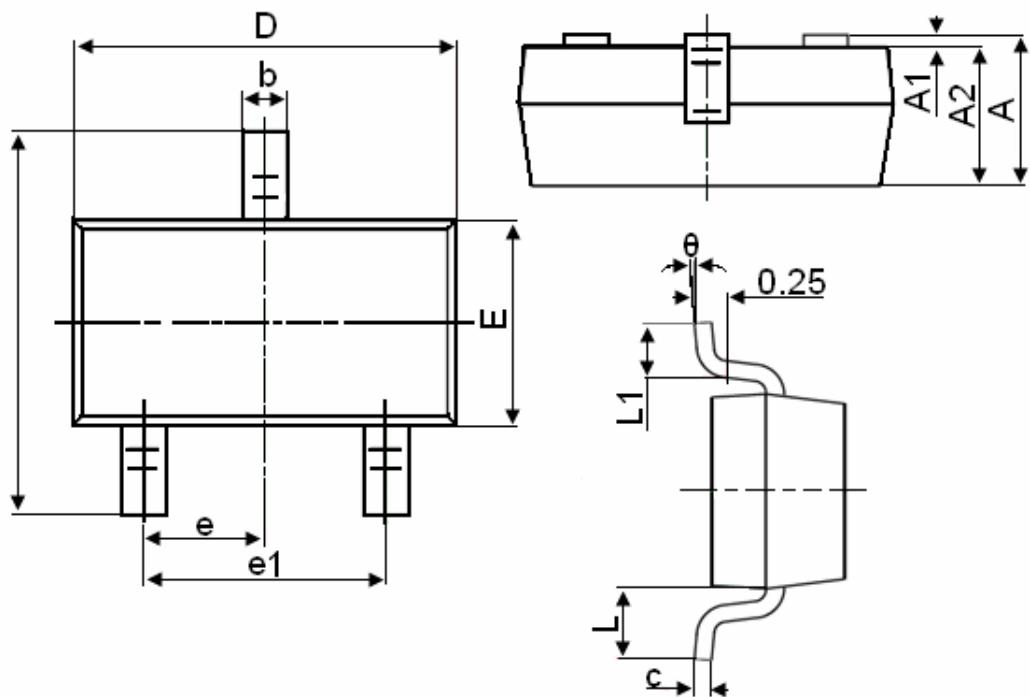
■ ELECTRICAL CHARACTERISTICS

($T_A=25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage ($I_D=10\mu\text{A}, V_{GS}=0\text{V}$)	BV_{DSS}	100	—	—	V
Gate Threshold Voltage ($I_D=1\text{mA}, V_{GS}= V_{DS}$)	$V_{GS(\text{th})}$	1.0	—	2.8	V
Diode Forward Voltage Drop ($I_{SD}=200\text{mA}, V_{GS}=0\text{V}$)	V_{SD}	—	—	1.5	V
Zero Gate Voltage Drain Current ($V_{GS}=0\text{V}, V_{DS}= 80\text{V}$)	I_{DSS}	—	—	1	μA
Gate Body Leakage ($V_{GS}=\pm 20\text{V}, V_{DS}=0\text{V}$)	I_{GSS}	—	—	± 10	μA
Static Drain-Source On-State Resistance ($I_D=120\text{mA}, V_{GS}=10\text{V}$)	$R_{DS(\text{ON})}$	—	3.5	6	Ω
Input Capacitance ($V_{GS}=0\text{V}, V_{DS}=25\text{V}, f=1\text{MHz}$)	C_{ISS}	—	—	40	pF
Common Source Output Capacitance ($V_{GS}=0\text{V}, V_{DS}=25\text{V}, f=1\text{MHz}$)	C_{OSS}	—	—	25	pF
Turn-ON Time ($V_{DS}=50\text{V}, I_D=200\text{mA}, R_{\text{GEN}}=25\Omega$)	$t_{(\text{on})}$	—	—	10	ns
Turn-OFF Time ($V_{DS}=50\text{V}, I_D=200\text{mA}, R_{\text{GEN}}=25\Omega$)	$t_{(\text{off})}$	—	—	20	ns

1. FR-5=1.0×0.75×0.062in.
2. Alumina=0.4×0.3×0.024in.99.5%alumina.
3. Pulse Width≤300 $\mu\text{ s}$; Duty Cycle≤2.0%.

SOT-23 Package Information



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

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